# **MSA1162GT1G**

# **General Purpose Amplifier Transistors**

# **PNP Surface Mount**

#### **Features**

- Moisture Sensitivity Level: 1
- This is a Pb-Free Device

#### **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>(BR)CBO</sub>	60	Vdc
Collector-Emitter Voltage	V <sub>(BR)CEO</sub>	50	Vdc
Emitter-Base Voltage	$V_{(BR)EBO}$	7.0	Vdc
Collector Current - Continuous	I <sub>C</sub>	100	mAdc
Collector Current - Peak	I <sub>C(P)</sub>	200	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation	$P_{D}$	200	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

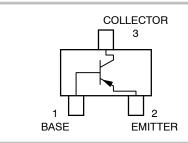
Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 2.0 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	50	-	Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = 10 μAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	60	-	Vdc
Emitter-Base Breakdown Voltage $(I_E = 10 \mu Adc, I_C = 0)$	V <sub>(BR)EBO</sub>	7.0	-	Vdc
Collector–Base Cutoff Current (V <sub>CB</sub> = 45 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	0.1	μAdc
	I <sub>CEO</sub>	- - -	0.1 2.0 1.0	μAdc μAdc mAdc
DC Current Gain (Note 1) (V <sub>CE</sub> = 6.0 Vdc, I <sub>C</sub> = 2.0 mAdc)	h <sub>FE</sub>	200	400	-
Collector-Emitter Saturation Voltage (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 10 mAdc)	V <sub>CE(sat)</sub>	-	0.5	Vdc
Current – Gain – Bandwidth Product (I <sub>C</sub> = 1 mA, V <sub>CE</sub> = 10.0 V, f = 10 MHz)	f <sub>T</sub>	80	_	MHz

1. Pulse Test: Pulse Width  $\leq$  300  $\mu s,\, D.C. \leq$  2%.



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SC-59 CASE 318D STYLE 1

#### **MARKING DIAGRAM**



62G = Device Code

M = Date Code\*

■ = Pb-Free Package

(Note: Microdot may be in either location)
\*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MSA1162GT1G	SC-59 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **MSA1162GT1G**

#### TYPICAL ELECTRICAL CHARACTERISTICS

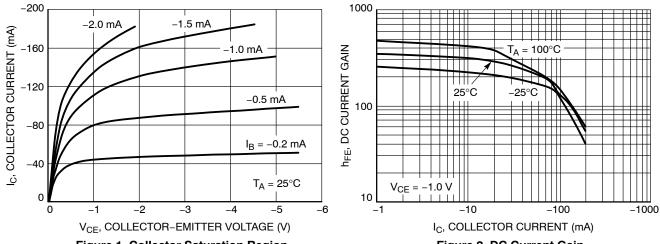


Figure 1. Collector Saturation Region

Figure 2. DC Current Gain

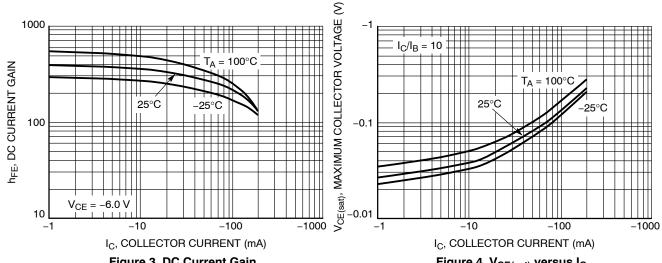




Figure 4. V<sub>CE(sat)</sub> versus I<sub>C</sub>

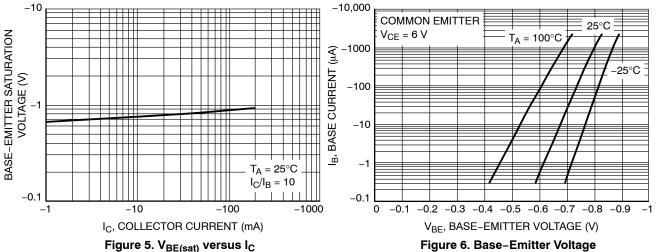


Figure 6. Base-Emitter Voltage





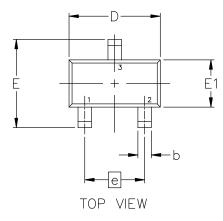
#### SC-59-3 2.90x1.50x1.15, 1.90P CASE 318D ISSUE J

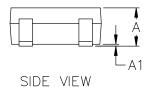
**DATE 15 FEB 2024** 

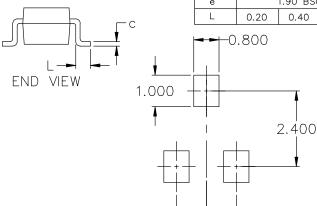
#### NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- 2. ALL DIMENSION ARE IN MILLIMETERS.

	MILLIMETERS		
DIM	MIN.	NOM.	MAX.
Α	1.00	1.15	1.30
A1	0.01	0.06	0.10
b	0.35	0.43	0.50
С	0.09	0.14	0.18
D	2.70	2.90	3.10
Е	2.50	2.80	3.00
E1	1.30	1.50	1.70
е	1.90 BSC		
L	0.20	0.40	0.60







0.950

# GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code

M = Date Code

= Pb-Free Package\*

(\*Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

#### RECOMMENDED MOUNTING FOOTPRINT\*

\* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

STYLE 1:	STYLE 2:	STYLE 3:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE
2. EMITTER	2. N.C.	<ol><li>ANODE</li></ol>
3. COLLECTOR	3. CATHODE	3. CATHODE

STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. CATHODE	PIN 1. CATHODE	PIN 1. ANODE
2. N.C.	2. CATHODE	2. CATHODE
3. ANODE	3. ANODE	<ol><li>ANODE/CATHODE</li></ol>

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DESCRIPTION:	SC-59-3 2.90x1.50x1.15, 1.90P		PAGE 1 OF 1

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